Degree competences to which the subject contributes

**Specific:**
1. Understanding the physics of semiconductors. Knowledge of microelectronic devices and their applications in nanotechnology, biophysics, photonics and communications. Ability to analyze the performance of electronic devices and integrated circuits.

**General:**
4. ABILITY TO IDENTIFY, FORMULATE, AND SOLVE PHYSICAL ENGINEERING PROBLEMS. Planning and solving physical engineering problems with initiative, making decisions and with creativity. Developing methods of analysis and problem solving in a systematic and creative way.
5. They will have acquired knowledge related to experiments and laboratory instruments and will be competent in a laboratory environment in the ICC field. They will know how to use the instruments and tools of telecommunications and electronic engineering and how to interpret manuals and specifications. They will be able to evaluate the errors and limitations associated with simulation measures and results.

**Transversal:**
1. EFFECTIVE USE OF INFORMATION RESOURCES - Level 3. Planning and using the information necessary for an academic assignment (a final thesis, for example) based on a critical appraisal of the information resources used.
2. EFFICIENT ORAL AND WRITTEN COMMUNICATION - Level 2. Using strategies for preparing and giving oral presentations. Writing texts and documents whose content is coherent, well structured and free of spelling and grammatical errors.
3. SELF-DIRECTED LEARNING - Level 3. Applying the knowledge gained in completing a task according to its relevance and importance. Deciding how to carry out a task, the amount of time to be devoted to it and the most suitable information sources.

Teaching methodology

There will be three theoretical and two practical weekly sessions.

Learning objectives of the subject

Understand the basics of semiconductor devices.
To know the basic principles and to be able to analyze quantitatively their behaviour.
You have the tools allowing to understand future devices.
### Study load

<table>
<thead>
<tr>
<th>Total learning time: 150h</th>
<th>Hours large group: 65h</th>
<th>43.33%</th>
</tr>
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<tbody>
<tr>
<td></td>
<td>Self study: 85h</td>
<td>56.67%</td>
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</table>

230471 - ELF - Physical Electronics
# Content

## 1. Semiconductor physics.

**Learning time:** 37h 30m  
Theory classes: 9h 45m  
Practical classes: 6h  
Self study (distance learning): 21h  
Guided activities: 0h 45m

**Description:**
1.2. Concentration of electrons and holes. Effective density of states. Fermi level.  
1.5. Generation and recombination of carriers. Lifetime. Quasi-Fermi levels.  

## 2. PN junction diode

**Learning time:** 37h 30m  
Theory classes: 9h 45m  
Practical classes: 6h  
Self study (distance learning): 21h  
Guided activities: 0h 45m

**Description:**
2.2. The pn junction under bias. Current-voltage characteristics of ideal diode.  
2.4. Dynamic resistance of the diode. Small-signal model.  
2.5. Metal-semiconductor junctions. Ohmic contact and Schottky diode.  
2.6. Introduction to optoelectronic devices: light emitting diode LED, laser diode, photodiode and solar cell.
There will be a final exam (EF) and mid-semester exam (EP). The students' participation in class of problems (P) and work to be done in groups will be also taken into account.

The final mark results from \( \max\{EF, 0.65 \times EF + 0.30 \times EP + 0.05 \times P\} \).

The work will assess general skills.
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Bibliography

Basic:

